Polarization Insensitive One-to-Six WDM Multicasting in a Silicon Nanowire

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Polarization Insensitive One-to-Six WDM Multicasting in a Silicon Nanowire

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Abstract: We present polarization insensitive one-to-six WDM multicasting based on non-degenerate four-wave mixing in a silicon nanowire with angled-pump scheme. Bit-error rate measurements are performed and error-free operation is achieved.

OCIS codes: (190.4380) Nonlinear optics, four-wave mixing; (190.4390) Nonlinear optics, integrated optics; (060.4255) Networks, multicast; (130.7405) Wavelength conversion devices.

1. Introduction

Multicasting is an important feature in a communication network, which can efficiently send a stream of information from a single source to multiple destinations [1], [2]. By using multicasting technology, the amount of network resources can be significantly reduced compared to unicast only networks. Optical layer multicasting could be implemented at a fixed wavelength by power splitting. An alternative is optical wavelength division multiplexing (WDM) multicasting, i.e., multicasting to different wavelengths. One of the most addressed techniques for WDM multicasting is all-optical multi-wavelength conversion (MWC), which replicates signals from one wavelength on multiple wavelengths. WDM multicasting has been demonstrated in different devices including semiconductor optical amplifiers (SOAs) [3], electroabsorption modulators (EAMs) [4], and highly nonlinear fibers (HNLFs) [5], [6], based on different nonlinear effects such as self-phase modulation (SPM), cross-phase modulation (XPM), cross-absorption modulation (XAM), and four-wave-mixing (FWM).

Recently, wavelength conversion in silicon nanowires has attracted considerable research interest due to its compactness, large conversion bandwidth [7] and complementary metal-oxide-semiconductor (CMOS) compatibility. Silicon nanowires have been utilized to demonstrate wavelength conversion at data rates from 10 Gb/s [8] to 640 Gb/s [9], and a sixteen-way multicasting operation of 40 Gb/s non return-to-zero (NRZ) data has also been demonstrated in silicon nanowires [10]. However, sixteen continuous wave (CW) tunable laser sources (TLSs) are needed to act as input signals and phase information is not preserved in the converted signals. Previously, we have demonstrated one-to-six multicasting operation based on dual-pump FWM in a silicon nanowire [11]. The FWM process is normally highly polarization dependent and an efficient FWM process only occurs when the input signal and pump waves are both aligned to either transverse-electric (TE) mode or transverse-magnetic (TM) mode. However, a polarization insensitive operation is desired since the state of polarization (SOP) of the input signal fluctuates with time and distance in a real transmission system.

In this paper, we report polarization-insensitive one-to-six WDM multicasting of 10 Gb/s differential phase-shift-keying (DPSK) data based on dual-pump FWM in a silicon nanowire using an angled-pump scheme [12]. Error-free performance is achieved for all six multicast signals while the polarization of the input data signal is continuously scrambled.

2. Experiment

Fig. 1. Experimental setup for polarization-insensitive wavelength multicasting of 10 Gb/s DPSK data in a silicon nanowire.

The experimental setup for the polarization-insensitive one-to-six WDM multicasting of a 10 Gb/s DPSK signal in a silicon nanowire is shown in Fig. 1. The pump waves are generated from external cavity lasers (ECL1 and ECL2) at 1545.7 nm and 1547.8 nm, respectively. The signal wave, generated by ECL3 at 1554.5 nm, is externally modulated by a Mach-Zehnder modulator (MZM) with a 10-Gb/s DPSK signal, encoded with a pseudo-random binary sequence (PRBS) of length $2^{21}-1$. All the pump and signal waves are amplified by erbium-doped fiber amplifiers...
(EDFAs), filtered by 1-nm optical band pass filters (OBPFs), and then combined by 3-dB couplers before being coupled into the silicon waveguide. The silicon nanowire is 1 cm long and its cross-sectional dimension is (H×W=300×450 nm²). It was fabricated on silicon-on-insulator (SOI) material using electron-beam lithography followed by reactive-ion etching. The silicon nanowire was inversely tapered at both ends and covered by a polymer waveguide for efficient coupling [13]. Two tapered fibers are used for coupling light into and out of the silicon waveguide. The polarization controller (PC) is used to adjust the polarization angle for the pump. At the output of the silicon waveguide, the converted signal (idler wave) is filtered out by two OBPFs, amplified by an EDFA in between, and detected by the 10-Gb/s DPSK receiver (shown by the dashed box in Fig. 1). In the receiver, the 10-Gb/s DPSK data signal is pre-amplified, filtered with a 1-nm OBPF and then demultiplexed by a one-symbol delay line interferometer (DLI). The output of the DLI is detected by a balanced photodetector (BPD), followed by a 10-Gb/s error analyzer (EA) for BER measurements. In order to test the polarization sensitivity, the SOP of the signal is continuously scrambled over the entire Poincaré sphere with a frequency ~113 kHz. The polarization angle of the co-polarized pumps is adjusted to minimize the power variation of one of the converted idlers at the output of the silicon nanowire while the input signal polarization is scrambled.

<table>
<thead>
<tr>
<th>Wavelength (nm)</th>
<th>Power (dBm)</th>
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<tbody>
<tr>
<td>1535</td>
<td>-80</td>
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<tr>
<td>1540</td>
<td>-60</td>
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<td>1545</td>
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<td>1560</td>
<td>15</td>
</tr>
<tr>
<td>1565</td>
<td>30</td>
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</table>

Fig. 2 shows the spectrum measured at the output of the silicon nanowire. The phase-preserved converted idlers are indicated by arrows.

To characterize the performance of the polarization-insensitive WDM multicasting, we measured the BER of the 10 Gb/s back-to-back and the multicast 10 Gb/s DPSK data signals without and with the input signal polarization scrambled, as shown in Fig. 3. Error-free operation was obtained for all the multicast signals. It is also seen that there is no error floor for all the converted idler signals. The maximum power penalty of the wavelength multicast signals is 8 dB at 10⁻⁹ for the converted idler \( \lambda_i \). The relatively large power penalty is mainly due to the residual CW pumps and low optical signal-to-noise ratio (OSNR) induced by the large amplified spontaneous emission (ASE) noise from the EDFA. In addition, the relatively low conversion efficiency for idler \( \lambda_i \) also contributes to the relatively large power penalty. Besides, the additional power penalties caused by the polarization scrambling of the signal are smaller than 2 dB. Fig. 3 (lower) shows the eye diagrams of the converted 10 Gb/s DPSK data signals without and with the input signal being polarization-scrambled. It is seen that all the converted idler signals have clear and open eyes which are comfortably error free. The receiver sensitivity of the converted idler signals could be improved by better filtering away the residual CW pump or increasing the pump power, which will result in an increased OSNR and increased conversion efficiency.
3. Conclusion
We have experimentally demonstrated polarization insensitive one-to-six WDM multicasting of 10 Gb/s DPSK data in a 1-cm long silicon nanowire based on dual-pump FWM. The polarization insensitive operation is realized with an angled-pump scheme. The phase information of the input DPSK signal has been successfully preserved and delivered from one wavelength to six multicast wavelengths using two pumps while the input signal polarization is continuously scrambled. In the BER measurement, all the multicast signals show error-free performance. The silicon nanowire could be useful for WDM multicasting applications in future WDM networks.

4. Reference